

FORM PTO-1449

LIST OF PATENTS AND PUBLICATIONS FOR
APPLICANT'S INFORMATION DISCLOSURE
STATEMENT

(Use several sheets if necessary)

ATTY. DOCKET NO.

10015150-1

APPLICATION NO.

CONFIRMATION NO.

APPLICANT

Zhizang Ch n, et al

FILING DATE

Her with

GROUP

j1046 U.S. PRO

09/88/981



REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS
Kas	1A	6,153,978	Nov 28 2000	Okamoto	315	169.3
	1B	6,137,213	Oct 24 2000	Moyer et al	313	309
	1C	6,137,272	Oct 24 2001	Liu et al	313	308
	1D	6,096,570	Aug 1 2000	Hattori	438	20
	1E	6,008,576	Dec 28 1999	Nakatani et al	313	495
	1F	5,877,594	Mar 2 1999	Miyano et al	315	169.1
	1G	5,557,596	Sep 17 1996	Gibson et al	369	101
	1H	5,541,473	Jul 30 1996	Duboc, Jr. et al	313	422
	1I	5,528,103	Jun 18 1996	Spindt et al	313	497
	1J	5,090,932	Feb 25 1992	Dieumegard et al	445	24
	1K	4,923,421	May 8 1990	Brodie et al	445	24

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	TRANSLATION	
							YES	NO
	1L							
	1M							
	1N							
	1O							
	1P							

OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)

Kas	1Q	Lee, Jin Ho, et al. "Fabrication and characterization of silicon field emitter arrays with focusing electrode by the chemical mechanical polishing process." J. Vac. Sci. Technol. B 16(2) Mar/Apr 1998, 811-814.
	1R	Endo, Yasuhiro, et al. "Microelectron gun with silicon field emitter." J. Vac. Sci. Technol. B 16(6), Nov/Dec 1998, 3082-3085.
	1S	Itoh, Junji, et al. "Fabrication of double-gated Si field emitter arrays for focused electron beam generation." J. Vac. Sci. Technol. B 13(5), Sep/Oct 1995, 1968-1972.

EXAMINER

Kas

DATE CONSIDERED

10/15/03